



DS1920 Temperature iButton

SPECIAL FEATURES

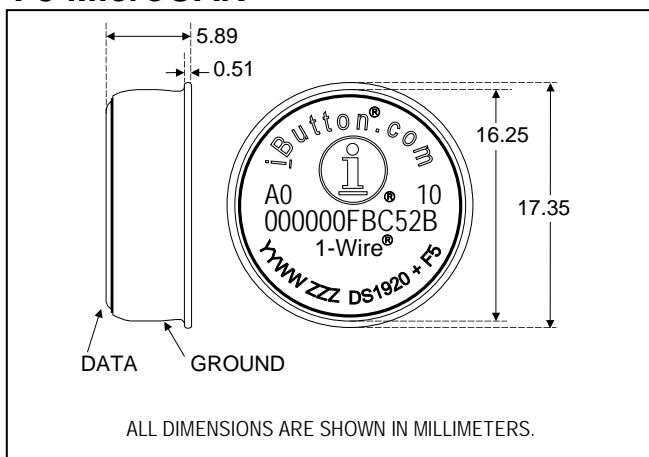
- Digital Thermometer Measures Temperatures from -55°C to $+100^{\circ}\text{C}$ in Typically 0.2s
- Zero Standby Power
- 0.5°C Resolution, Digital Temperature Reading is Two's Complement of $^{\circ}\text{C}$ Value
- Access to Internal Counters Allows Increased Resolution Through Interpolation
- Reduces control, Address, Data, and Power to a Single Data Contact
- 8-Bit Device-Generated CRC for Data Integrity
- 8-Bit Family Code Specifies DS1920 Communications Requirements to Reader
- Special Command Set Allows User to Skip ROM Section and Perform Temperature Measurements Simultaneously for All Devices on the Bus
- 2 Bytes of EEPROM to Be Used Either as Alarm Triggers or User Memory
- Alarm Search Directly Indicates Which Device Senses Alarming Temperatures

ORDERING INFORMATION

PART	PIN-PACKAGE
DS1920-F5+	F5 MicroCAN

+Denotes a lead(Pb)-free/RoHS-compliant package.

F5 MicroCAN



COMMON iButton FEATURES

- Unique, Factory-Lasered and Tested 64-Bit Registration Number (8-Bit Family Code + 48-Bit Serial Number + 8-Bit CRC Tester) Assures Absolute Traceability Because No Two Parts Are Alike
- Multidrop Controller for MicroLAN
- Digital Identification and Information by Momentary Contact
- Chip-Based Data Carrier Compactly Stores Information
- Data Can Be Accessed While Affixed To Object
- Economically Communicates to Bus Master with a Single Digital Signal at 16.3kbps
- Standard 16mm Diameter and 1-Wire[®] Protocol Ensure Compatibility with iButton[®] Family
- Button Shape is Self-Aligning with Cup-Shaped Probes
- Durable Stainless Steel Case Engraved with Registration Number Withstands Harsh Environments
- Easily Affixed with Self-Stick Adhesive Backing, Latched by Its Flange, or Locked with a Ring Pressed Onto Its Rim
- Presence Detector Acknowledges When Reader First Applies Voltage

EXAMPLES OF ACCESSORIES

DS9096P	Self-Stick Adhesive Pad
DS9101	Multipurpose Clip
DS9093RA	Mounting Lock Ring
DS9093F	Snap-In Fob
DS9092	iButton Probe

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iButton DESCRIPTION

The DS1920 Temperature iButton provides 9-bit temperature readings, which indicate the temperature of the device. Information is sent to/from the DS1920 over a 1-Wire interface. Power for reading, writing, and performing temperature conversions is derived from the data line itself. Because each DS1920 contains a unique silicon serial number, multiple DS1920s can exist on the same 1-Wire bus. This allows for placing temperature sensors in many different places. Applications where this feature is useful include HVAC environmental controls, sensing temperatures inside buildings, equipment or machinery, and in process monitoring and control.

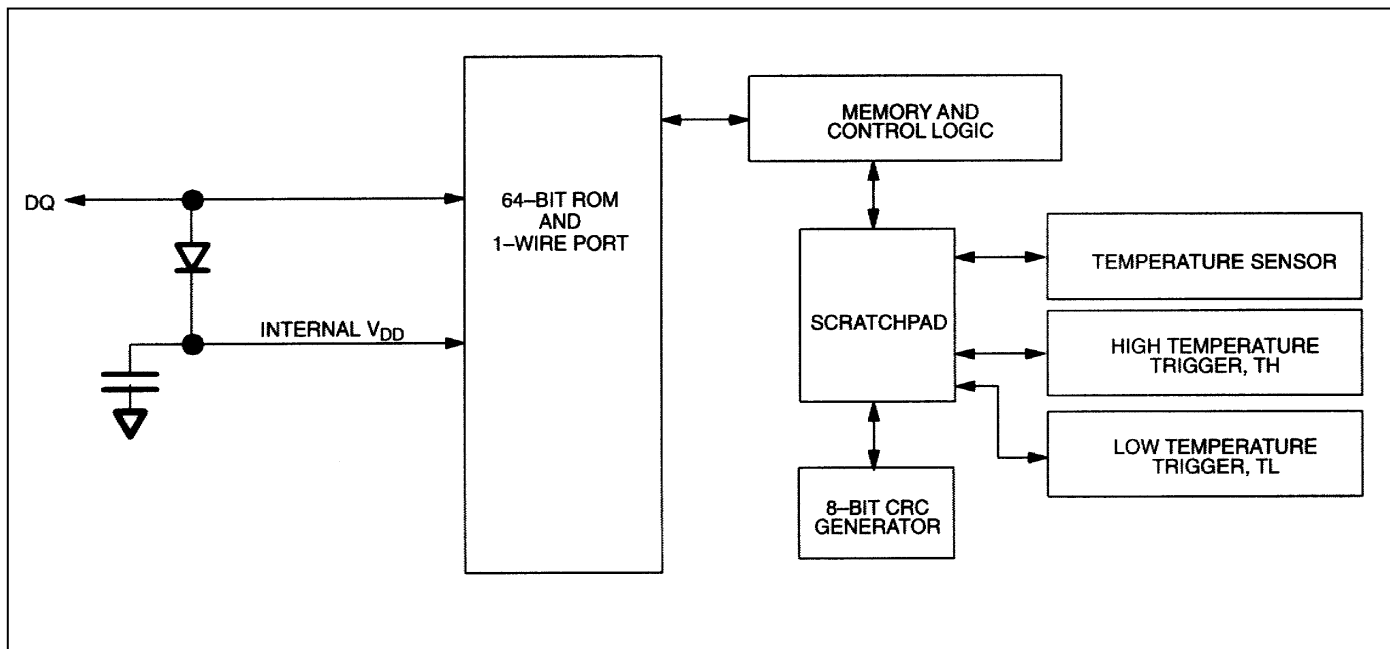
OVERVIEW

The block diagram of Figure 1 shows the major components of the DS1920. The DS1920 has three main data components: 1) 64-bit lasered ROM, 2) temperature sensor, and 3) nonvolatile temperature alarm triggers TH and TL. The device derives its power from the 1-Wire communication line by storing energy on an internal capacitor during periods of time when the signal line is high and continues to operate off this power source during the low times of the 1-Wire line until it returns high to replenish the parasite (capacitor) supply.

Communication to the DS1920 is via a 1-Wire port. With the 1-Wire port, the memory and control functions will not be available before the ROM function protocol has been established. The master must first provide one of five ROM function commands: 1) Read ROM, 2) Match ROM, 3) Search ROM, 4) Skip ROM, or 5) Alarm Search. These commands operate on the 64-bit lasered ROM portion of each device and can single out a specific device if many are present on the 1-Wire line as well as indicate to the bus master how many and what types of devices are present. After a ROM function sequence has been successfully executed, the memory and control functions are accessible and the master may then provide any one of the five memory and control function commands.

One control function command instructs the DS1920 to perform a temperature measurement. The result of this measurement will be placed in the DS1920's scratchpad memory, and may be read by issuing a memory function command, which reads the contents of the scratchpad memory. The temperature alarm triggers TH and TL consist of 1 byte of EEPROM each. If the alarm search command is not applied to the DS1920, these registers may be used as general-purpose user memory. Writing TH and TL is done using a memory function command. Read access to these registers is through the scratchpad. All data is read and written least significant bit first.

DS1920 BLOCK DIAGRAM Figure 1



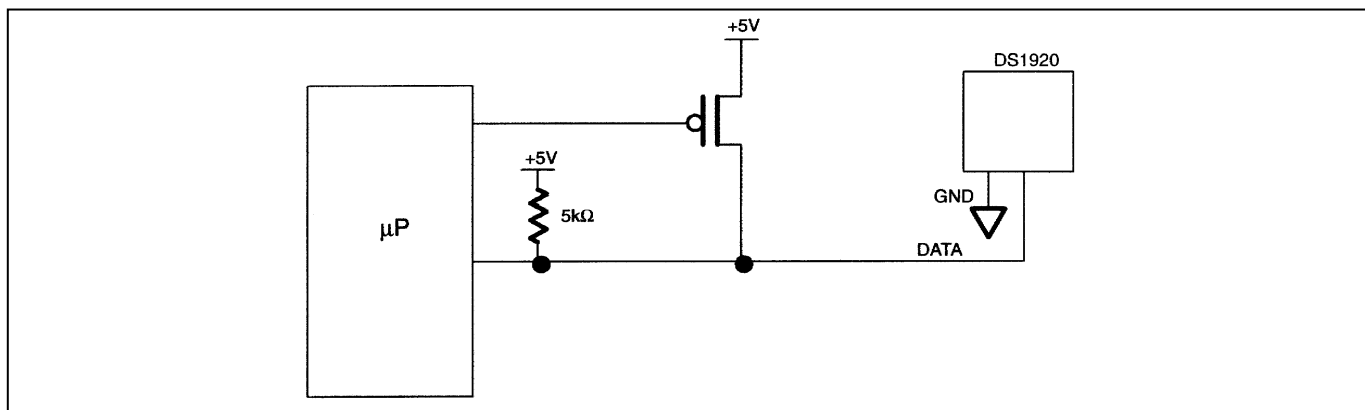
PARASITE POWER

The block diagram (Figure 1) shows the parasite-powered circuitry. This circuitry “steals” power whenever the data contact is high. Data will provide sufficient power as long as the specified timing and voltage requirements are met (see the *I-Wire Bus System* section). The advantage of parasite power is that no local power source is needed for remote sensing of temperature.

In order for the DS1920 to be able to perform accurate temperature conversions, sufficient power must be provided over the data line when a temperature conversion is taking place. The DS1920 requires a current during conversion of up to 1mA, therefore, the data line will not have sufficient drive due to the 5 k Ω pullup resistor. This problem is particularly acute if several DS1920s are on the same data line and attempting to convert simultaneously.

The way to assure that the DS1920 has sufficient supply current is to provide a strong pullup on the data line whenever temperature conversion or copying to the EEPROM is taking place. This may be accomplished by using a MOSFET to connect the data line directly to the power supply as shown in Figure 2. The data line must be switched over to the strong pullup within 10 μ s maximum after issuing a command that involves copying to the EEPROM or initiates a temperature conversion.

STRONG PULLUP FOR SUPPLYING DS1920 DURING TEMPERATURE CONVERSION Figure 2



OPERATION—MEASURING TEMPERATURE

The DS1920 measures temperatures through the use of an on-board proprietary temperature measurement technique. A block diagram of the temperature measurement circuitry is shown in Figure 3.

The DS1920 measures temperature by counting the number of clock cycles that an oscillator with a low temperature coefficient goes through during a gate period determined by a high temperature coefficient oscillator. The counter is preset with a base count that corresponds to -55°C . If the counter reaches 0 before the gate period is over, the temperature register, which is also preset to the -55°C value, is incremented, indicating that the temperature is higher than -55°C .

At the same time, the counter is then preset with a value determined by the slope accumulator circuitry. The counter is then clocked again until it reaches 0. If the gate period is still not finished, then this process repeats.

The slope accumulator compensates for the nonlinear behavior of the oscillators over temperature, yielding a high-resolution temperature measurement. This is done by changing the number of counts necessary for the counter to go through for each incremental degree in temperature. To obtain the desired resolution, therefore, both the value of the counter and the number of counts per degree C (the value of the slope accumulator) at a given temperature must be known.

Internally, this calculation is done inside the DS1920 to provide 0.5°C resolution. The temperature reading is provided in a 16-bit, sign-extended two's complement reading. Table 1 describes the exact relationship of output data to measured temperature. The data is transmitted serially over the 1-Wire interface. The DS1920 can measure temperature over the range of -55°C to $+100^{\circ}\text{C}$ in 0.5°C increments. For Fahrenheit usage, a lookup table or conversion factor must be used.

Note that temperature is represented in the DS1920 in terms of a $1/2^{\circ}\text{C}$ LSB, yielding the following 9-bit format:

MSB								LSB
1	1	1	0	0	1	1	1	0

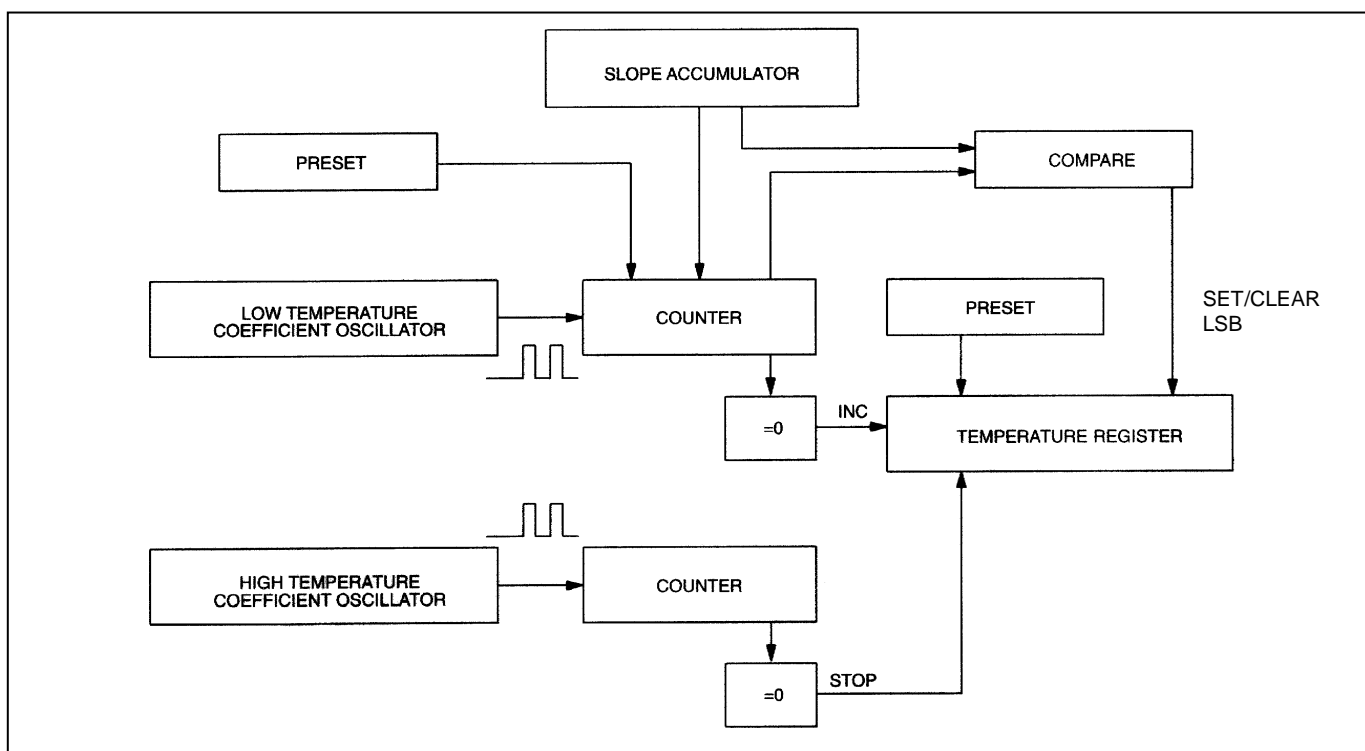
= -25°C

The most significant (sign) bit is duplicated into all of the bits in the upper MSB of the 2-byte temperature register in memory. This “sign-extension” yields the 16-bit temperature readings as shown in Table 1.

Higher resolutions may be obtained by the following procedure. First, read the temperature, and truncate the 0.5°C bit (the LSB) from the read value. This value is TEMP_READ. The value left in the counter may then be read. This value is the count remaining (COUNT_REMAIN) after the gate period has ceased. The last value needed is the number of counts per degree C (COUNT_PER_C) at that temperature. The actual temperature may be then be calculated by the user using the following formula:

$$\text{TEMPERATURE} = \text{TEMP_READ} - 0.25 + \frac{(\text{COUNT_PER_C} - \text{COUNT_REMAIN})}{\text{COUNT_PER_C}}$$

TEMPERATURE MEASURING CIRCUITRY Figure 3



TEMPERATURE/DATA RELATIONSHIPS Table 1

TEMPERATURE	DIGITAL OUTPUT (BINARY)	DIGITAL OUTPUT (HEX)
+100°C	00000000 11001000	00C8h
+25°C	00000000 00110010	0032h
+½°C	00000000 00000001	0001h
+0°C	00000000 00000000	0000h
-½°C	11111111 11111111	FFFFh
-25°C	11111111 11001110	FFCEh
-55°C	11111111 10010010	FF92h

OPERATION—ALARM SIGNALING

After the DS1920 has performed a temperature conversion, the temperature value is compared to the trigger values stored in TH and TL. Since these registers are 8 bits only, the 0.5°C bit is ignored for comparison. The most significant bit of TH or TL directly corresponds to the sign bit of the 16-bit temperature register. If the result of a temperature measurement is higher than TH or lower than TL, an alarm flag inside the device is set. This flag is updated with every temperature measurement. As long as the alarm flag is set, the DS1920 will respond to the alarm search command. This allows many DS1920s to be connected in parallel doing simultaneous temperature measurements. If somewhere the temperature exceeds the limits, the alarming device(s) can be identified and read immediately without having to read nonalarming devices.

64-BIT LASERED ROM

Each DS1920 contains a unique ROM code that is 64 bits long. The first 8 bits are a 1-Wire family code (DS1920 code is 10h). The next 48 bits are a unique serial number. The last 8 bits are a CRC of the first 56 bits. (See Figure 4.) The 64-bit ROM and ROM Function Control section allow the DS1920 to operate as a 1-Wire device and follow the 1-Wire protocol detailed in the *1-Wire Bus System* section. The memory and control functions of the DS1920 are not accessible until the ROM function protocol has been satisfied. This protocol is described in the ROM function protocol flowchart (Figure 5). The 1-Wire bus master must first provide one of five ROM function commands: 1) Read ROM, 2) Match ROM, 3) Search ROM, 4) Skip ROM, or 5) Alarm Search. After a ROM function sequence has been successfully executed, the functions specific to the DS1920 are accessible and the bus master may then provide any one of the five memory and control function commands.

CRC GENERATION

The DS1920 has an 8-bit CRC stored in the most significant byte of the 64-bit ROM. The bus master can compute a CRC value from the first 56 bits of the 64-bit ROM and compare it to the value stored within the DS1920 to determine if the ROM data has been received error-free by the bus master. The equivalent polynomial function of this CRC is:

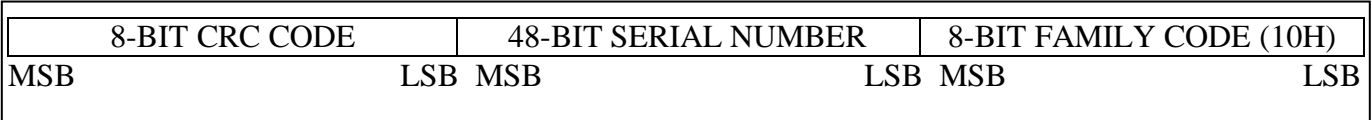
$$\text{CRC} = X^8 + X^5 + X^4 + 1$$

The DS1920 also generates an 8-bit CRC value using the same polynomial function shown above and provides this value to the bus master to validate the transfer of data bytes. In each case where a CRC is used for data transfer validation, the bus master must calculate a CRC value using the polynomial function given above and compare the calculated value to either the 8-bit CRC value stored in the 64-bit ROM portion of the DS1920 (for ROM reads) or the 8-bit CRC value computed within the DS1920 (which is read as a 9th byte when the scratchpad is read). The comparison of CRC values and decision to continue with an operation are determined entirely by the bus master. There is no circuitry inside the DS1920 that prevents a command sequence from proceeding if the CRC stored in or calculated by the DS1920 does not match the value generated by the bus master.

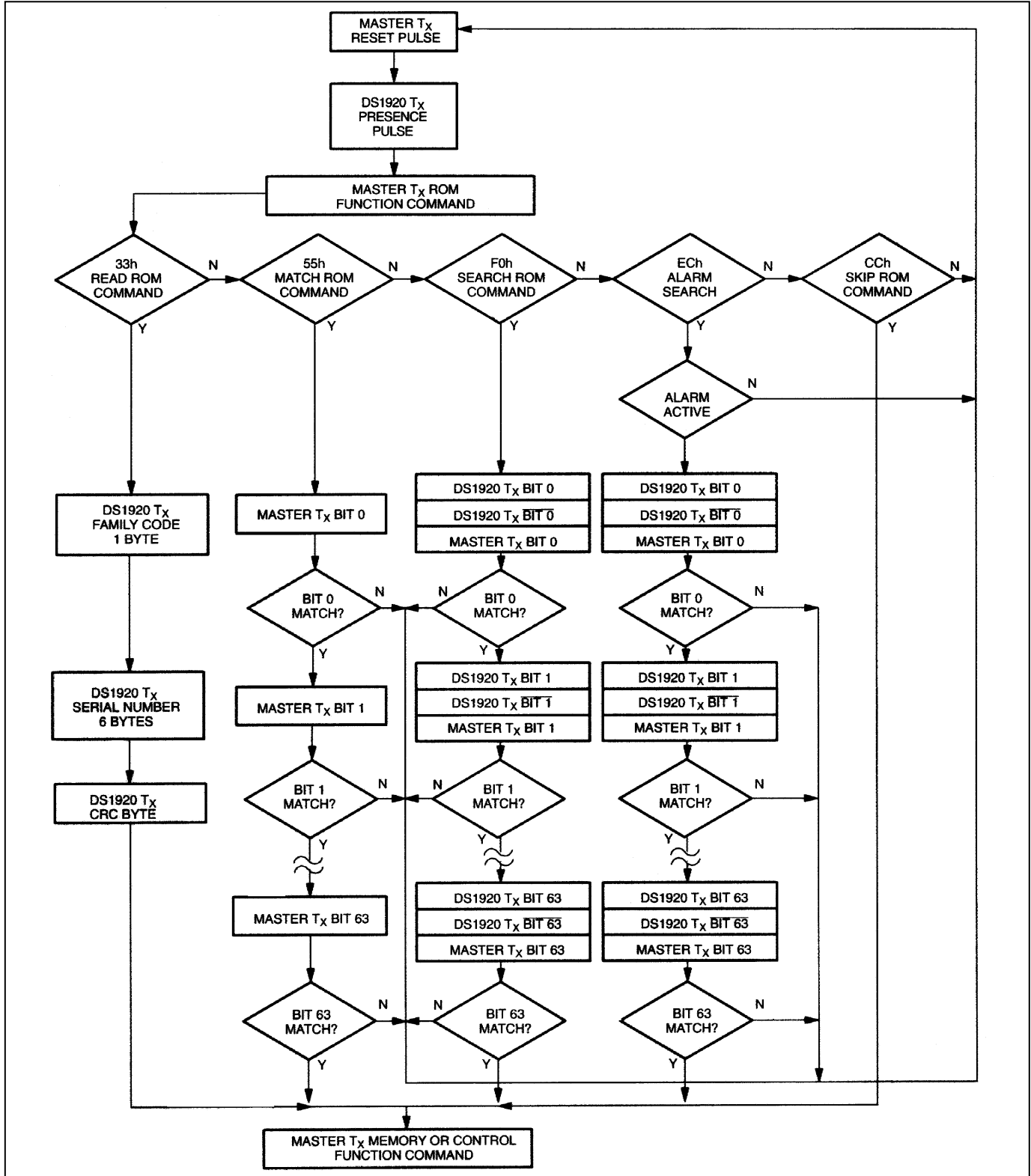
The 1-Wire CRC can be generated using a polynomial generator consisting of a shift register and XOR gates as shown in Figure 6. Additional information about the Maxim 1-Wire Cyclic Redundancy Check is available in the *Book of iButton Standards*.

The shift register bits are first initialized to 0. For the ROM section, starting with the least significant bit of the family code, 1 bit at a time is shifted in. After the 8th bit of the family code has been entered, then the serial number is entered. After the 48th bit of the serial number has been entered, the shift register contains the CRC value. Shifting in the 8 bits of CRC should return the shift register to all 0s.

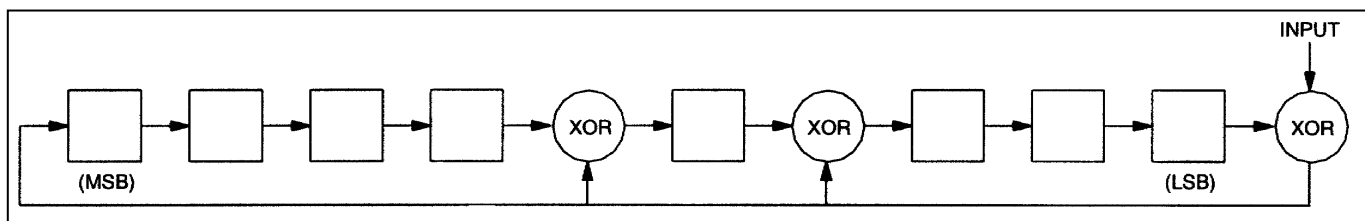
64-BIT LASERED ROM Figure 4



ROM FUNCTIONS FLOWCHART Figure 5



1-Wire CRC CODE Figure 6



MEMORY

The DS1920's memory is organized as shown in Figure 7. The memory consists of a scratchpad and 2 bytes of EEPROM that store the high and low temperature triggers TH and TL. The scratchpad helps insure data integrity when communicating over the 1-Wire bus. Data is first written to the scratchpad where it can be read back. After the data has been verified, a copy scratchpad command will transfer the data to the EEPROM. This process ensures data integrity when modifying the memory.

The scratchpad is organized as 8 bytes of memory. The first 2 bytes contain the measured temperature information. The 3rd and 4th bytes are volatile copies of TH and TL and are refreshed with every power-on reset. The next 2 bytes are not used; upon reading back, however, they will appear as all logic 1s. The 7th and 8th bytes are count registers, which may be used in obtaining higher temperature resolution (see the *Operation—Measuring Temperature* section).

There is a 9th byte that may be read with a Read Scratchpad command. This byte is a cyclic redundancy check (CRC) over all of the 8 previous bytes. This CRC is implemented as described in the *CRC Generation* section.

DS1920 MEMORY MAP Figure 7

SCRATCHPAD	BYTE	EEPROM
TEMPERATURE LSB	0	
TEMPERATURE MSB	1	
TH/USER BYTE 1	2	TH/USER BYTE 1
TL/USER BYTE 2	3	TL/USER BYTE 2
RESERVED	4	
RESERVED	5	
COUNT REMAIN	6	
COUNT PER °C	7	
CRC	8	

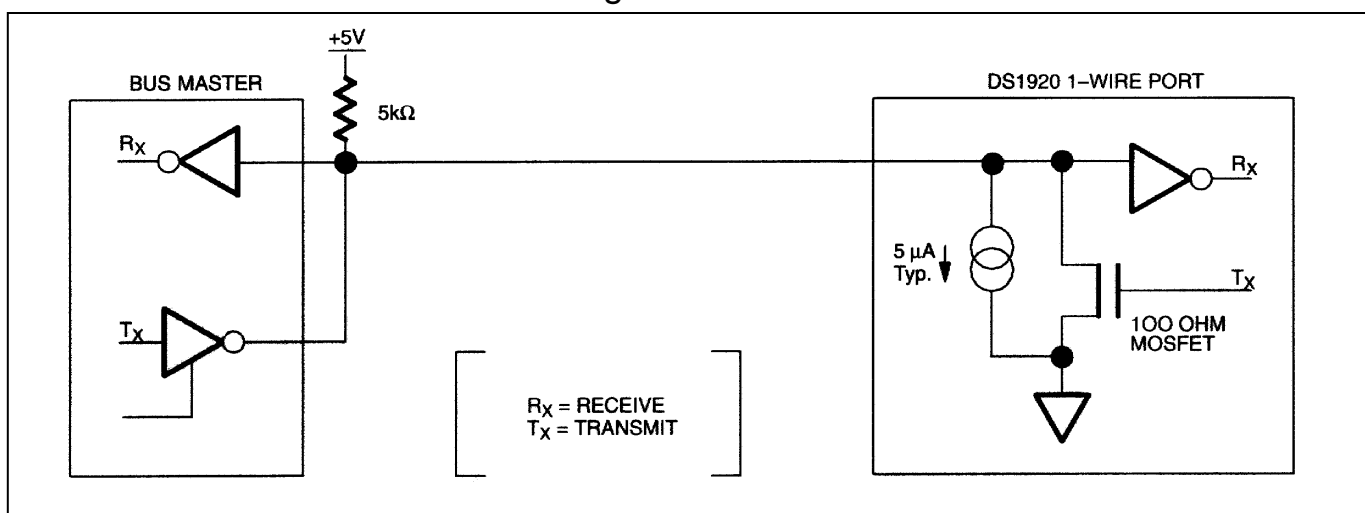
1-Wire BUS SYSTEM

The 1-Wire bus is a system that has a single bus master and one or more slaves. The DS1920 behaves as a slave. The discussion of this bus system is broken down into three topics: hardware configuration, transaction sequence, and 1-Wire signaling (signal types and timing).

HARDWARE CONFIGURATION

The 1-Wire bus has only a single line by definition; it is important that each device on the bus be able to drive it at the appropriate time. To facilitate this, each device attached to the 1-Wire bus must have open-drain or 3-state outputs. The 1-Wire port of the DS1920 (data contact) is open drain with an internal circuit equivalent to that shown in Figure 8. A multidrop bus consists of a 1-Wire bus with multiple slaves attached. The 1-Wire bus requires a pullup resistor of approximately $5k\Omega$. The idle state for the 1-Wire bus is high. If for any reason a transaction needs to be suspended, the bus **MUST** be left in the idle state if the transaction is to resume. If this does not occur and the bus is left low for more than $120\mu s$, one or more of the devices on the bus will be reset.

HARDWARE CONFIGURATION Figure 8



TRANSACTION SEQUENCE

The protocol for accessing the DS1920 via the 1-Wire port is as follows:

- Initialization
- ROM Function Command
- Memory/Control Function Command
- Transaction/Data

INITIALIZATION

All transactions on the 1-Wire bus begin with an initialization sequence. The initialization sequence consists of a reset pulse transmitted by the bus master followed by presence pulse(s) transmitted by the slave(s).

The presence pulse lets the bus master know that the DS1920 is on the bus and is ready to operate. For more details, see the *1-Wire Signaling* section.

ROM FUNCTION COMMANDS

Once the bus master has detected a presence pulse, it can issue one of the five ROM function commands. All ROM function commands are eight bits long. A list of these commands follows (see the flowchart in Figure 5).

Read ROM [33h]

This command allows the bus master to read the DS1920's 8-bit family code, unique 48-bit serial number, and 8-bit CRC. This command can only be used if there is a single DS1920 on the bus. If more than one slave is present on the bus, a data collision will occur when all slaves try to transmit at the same time (open drain will produce a wired-AND result).

Match ROM [55h]

The match ROM command, followed by a 64-bit ROM sequence, allows the bus master to address a specific DS1920 on a multidrop bus. Only the DS1920 that exactly matches the 64-bit ROM sequence will respond to the subsequent memory function command. All slaves that do not match the 64-bit ROM sequence will wait for a reset pulse. This command can be used with a single or multiple devices on the bus.

Skip ROM [CCh]

This command can save time in a single drop bus system by allowing the bus master to access the memory functions without providing the 64-bit ROM code. If more than one slave is present on the bus and a read command is issued following the Skip ROM command, data collision will occur on the bus as multiple slaves transmit simultaneously (open-drain pulldowns will produce a wired-AND result). The Skip ROM command is useful to address all DS1920s on the bus to do a temperature conversion. Since the DS1920 uses a special command set, other device types will not respond to these commands.

Search ROM [F0h]

When a system is initially brought up, the bus master might not know the number of devices on the 1-Wire bus or their 64-bit ROM codes. The search ROM command allows the bus master to use a process of elimination to identify the 64-bit ROM codes of all slave devices on the bus. The ROM search process is the repetition of a simple, three-step routine: read a bit, read the complement of the bit, then write the desired value of that bit. The bus master performs this simple, three-step routine on each bit of the ROM. After one complete pass, the bus master knows the contents of the ROM in one device. The remaining number of devices and their ROM codes may be identified by additional passes. Refer to Chapter 5 of the *Book of iButton Standards* for a comprehensive discussion of a ROM Search, including an actual example.

Alarm Search [ECh]

The flowchart of this command is identical to the Search ROM command; however, the DS1920 will respond to this command only if an alarm condition has been encountered at the last temperature measurement. An alarm condition is defined as a temperature higher than TH or lower than TL. The alarm condition remains set as long as the DS1920 is powered up or until another temperature measurement reveals a nonalarming value. For alarming, the trigger values stored in EEPROM are taken into account. If an alarm condition exists and the TH or TL settings are changed, another temperature conversion should be done to validate any alarm conditions.

MEMORY AND CONTROL FUNCTION COMMANDS

The following command protocols are summarized in Table 2, and by the flowchart of Figure 9.

Write Scratchpad [4Eh]

This command writes to the scratchpad of the DS1920, starting at address 2. The next 2 bytes written will be saved in scratchpad memory, at address locations 2 and 3. Writing may be terminated at any point by issuing a reset. However, if a reset occurs before both bytes have been completely sent, the contents of these bytes will be indeterminate. Bytes 2 and 3 can be read and written; all other bytes are read only.

Read Scratchpad [BEh]

This command reads the complete scratchpad. After the last byte of the scratchpad is read, the bus master will receive an 8-bit CRC of all scratchpad bytes. If not all locations are to be read, the master may issue a reset to terminate reading at any time.

Copy Scratchpad [48h]

This command copies from the scratchpad into the EEPROM of the DS1920, storing the temperature trigger bytes in nonvolatile memory. The bus master has to enable a strong pullup for at least 10 ms immediately after issuing this command.

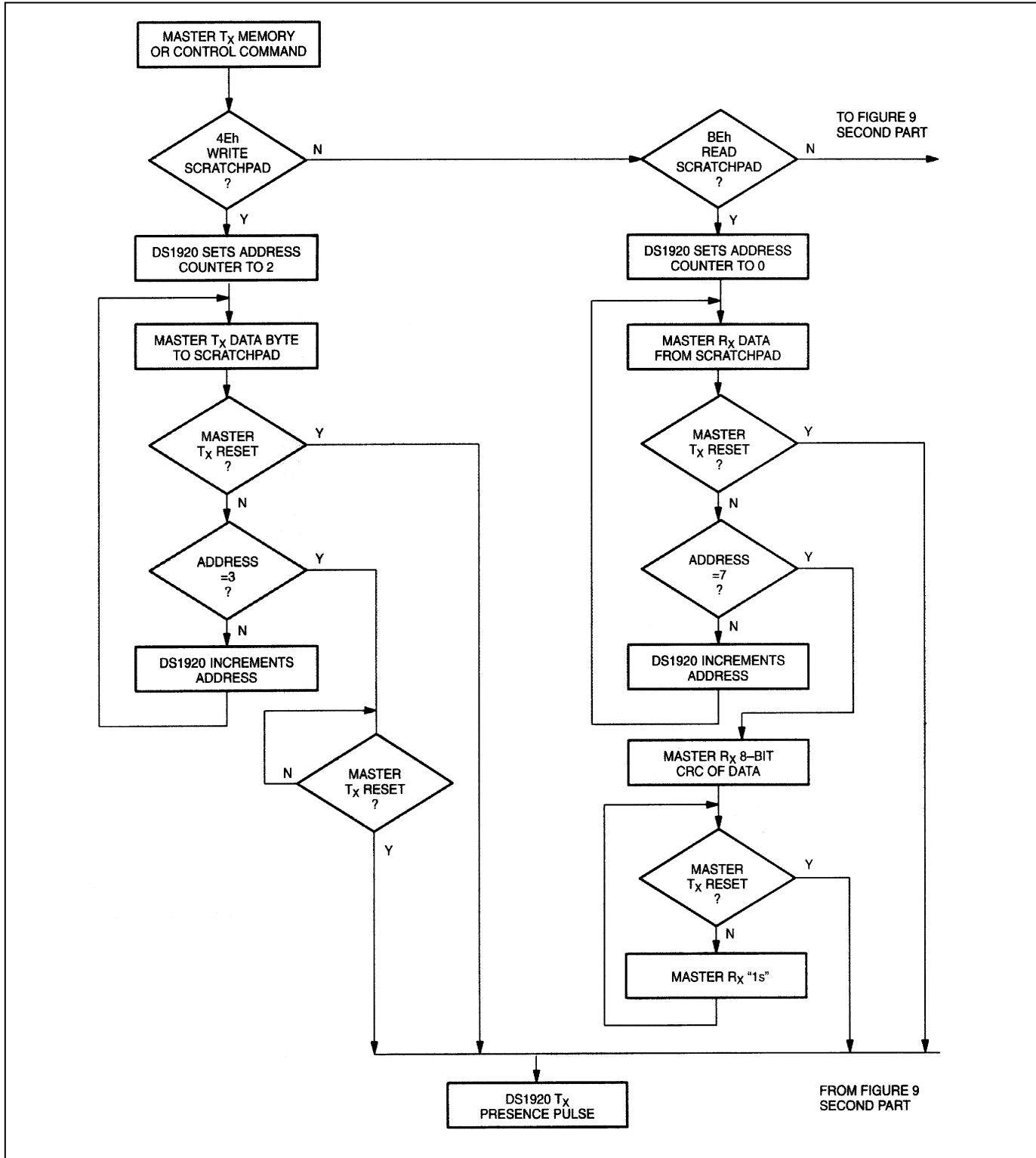
Convert Temperature [44h]

This command begins a temperature conversion. No further data is required. The bus master has to enable a strong pullup for 0.75 seconds immediately after issuing this command.

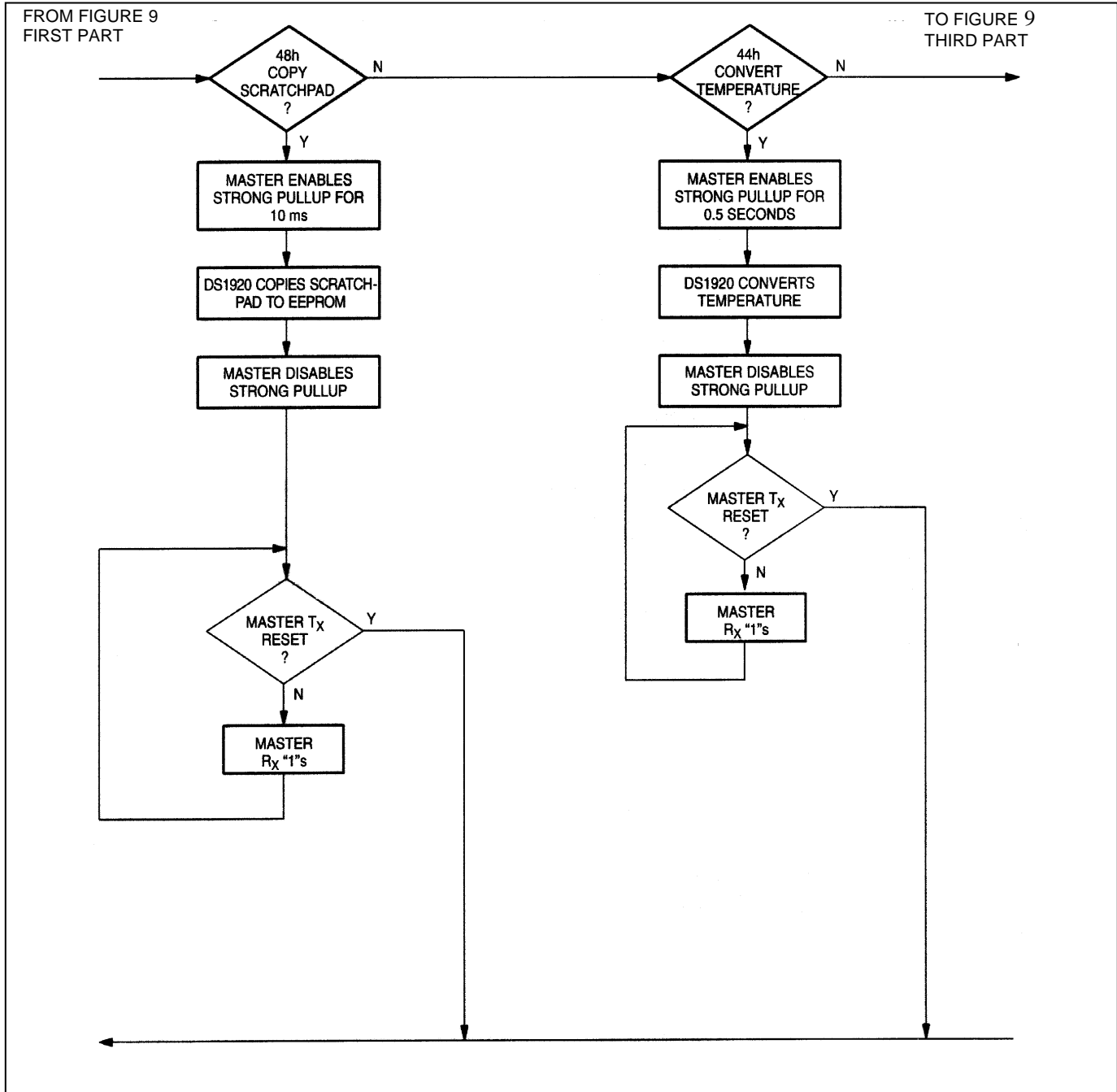
Recall [B8h]

This command recalls the temperature trigger values stored in EEPROM to the scratchpad. This recall operation happens automatically upon power-up to the DS1920 as well, so valid data is available in the scratchpad as soon as the device has power applied.

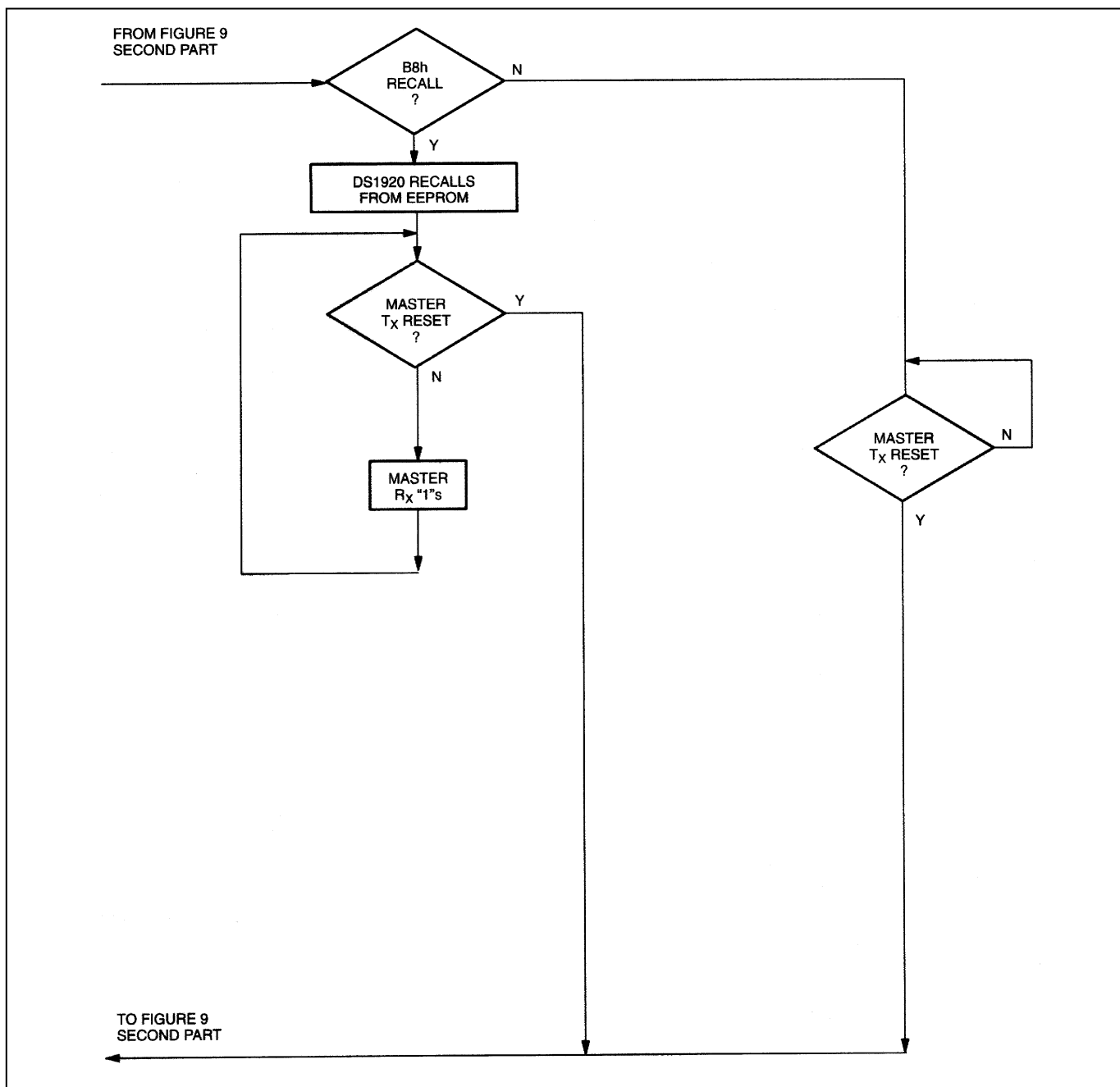
MEMORY AND CONTROL FUNCTIONS FLOWCHART Figure 9



MEMORY AND CONTROL FUNCTIONS FLOWCHART (continued) Figure 9



MEMORY AND CONTROL FUNCTIONS FLOWCHART (continued) Figure 9



1-Wire SIGNALING

The DS1920 requires strict protocols to ensure data integrity. The protocol consists of five types of signaling on one line: Reset Sequence with Reset Pulse and Presence Pulse, Write 0, Write 1, Read Data and Strong Pullup. All these signals except Presence Pulse are initiated by the bus master. The initialization sequence required to begin any communication with the DS1920 is shown in Figure 10. A Reset Pulse followed by a Presence Pulse indicates the DS1920 is ready to accept a ROM command. The bus master transmits (Tx) a Reset Pulse (t_{RSTL} , minimum 480 μ s). The bus master then releases the line and goes into receive mode (Rx). The 1-Wire bus is pulled to a high state via the pullup resistor. After detecting the rising edge on the 1-Wire line, the DS1920 waits (t_{PDH} , 15–60 μ s) and then transmits the Presence Pulse (t_{PDL} , 60–240 μ s).

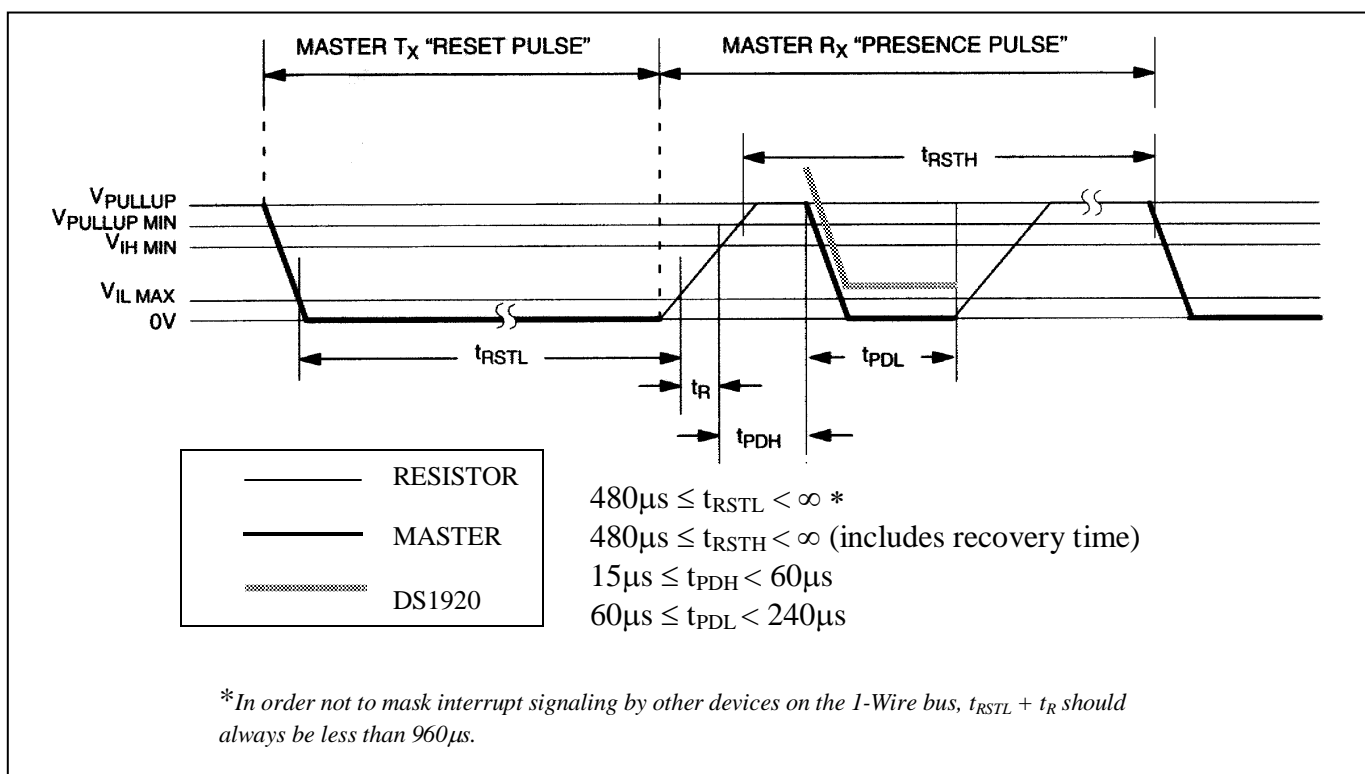
READ/WRITE TIME SLOTS

The definitions of write and read time slots are illustrated in Figure 11. All time slots are initiated by the master driving the data line low. The falling edge of the data line synchronizes the DS1920 to the master by triggering a delay circuit in the DS1920. During write time slots, the delay circuit determines when the DS1920 will sample the data line. For a read data time slot, if a 0 is to be transmitted, the delay circuit determines how long the DS1920 will hold the data line low overriding the 1 generated by the master. If the data bit is a 1, the DS1920 will leave the read data time slot unchanged.

STRONG PULLUP

To provide energy for a temperature conversion or for copying data from the scratchpad to the EEPROM, a low-impedance pullup of the 1-Wire bus to 5V is required just after the corresponding command has been sent by the master. During temperature conversion or copying the scratchpad, the bus master controls the transition from a state where the data line is idling high via the pullup resistor to a state where the data line is actively driven to 5V, providing a minimum of 1mA of current for each DS1920 doing temperature conversion. This low impedance pullup should be active for 0.75 seconds for temperature conversion or at least 10ms for copying to the scratchpad. After that, the data line returns to an idle high state controlled by the pullup resistor. The low-impedance pullup does not affect other devices on the 1-Wire bus. Therefore, it is possible to multidrop other 1-Wire devices with the DS1920.

INITIALIZATION PROCEDURE “RESET AND PRESENCE PULSES” Figure 10

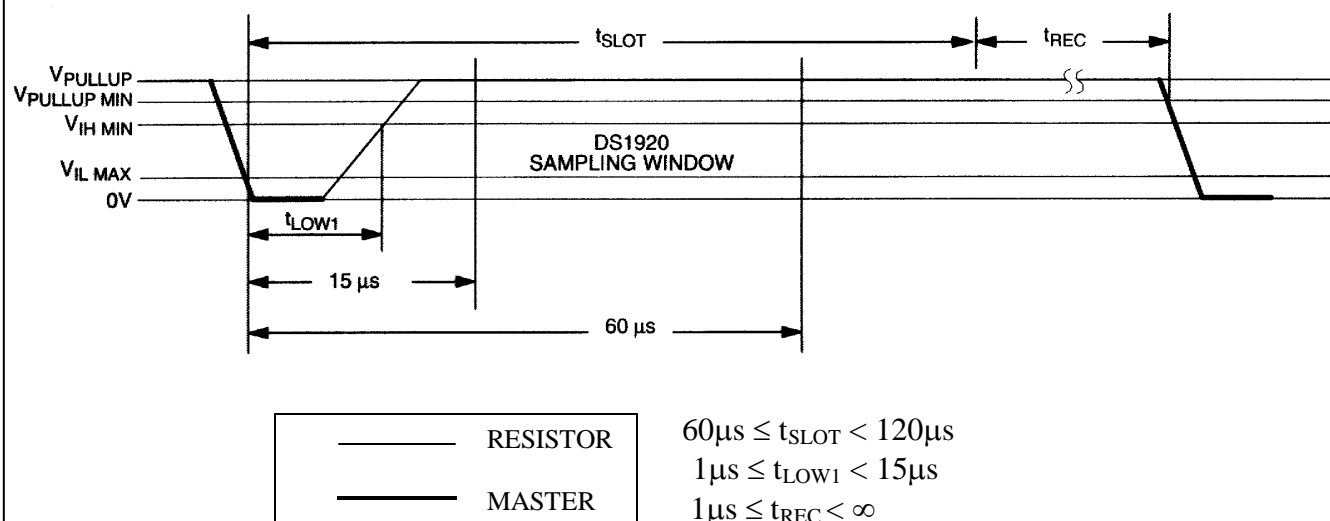


DS1920 MEMORY AND CONTROL FUNCTION COMMANDS Table 2

INSTRUCTION	DESCRIPTION	PROTOCOL	1-Wire BUS AFTER ISSUING PROTOCOL	NOTES
TEMPERATURE CONVERSION COMMANDS				
Convert Temperature	Initiates temperature conversion	44h	strong pullup	1
MEMORY COMMANDS				
Read Scratchpad	Reads bytes from scratchpad and reads CRC byte.	BEh	<read up to 9 data bytes>	
Write Scratchpad	Writes bytes into scratchpad at addresses 2 and 3 (TH and TL temperature triggers).	4Eh	<write data into 2 bytes at addr. 2 and addr. 3>	
Copy Scratchpad	Copies Scratchpad into nonvolatile memory (addresses 2 and 3 only).	48h	strong pullup	2
Recall	Recalls values stored in nonvolatile memory into scratchpad (temperature triggers).	B8h	idle	

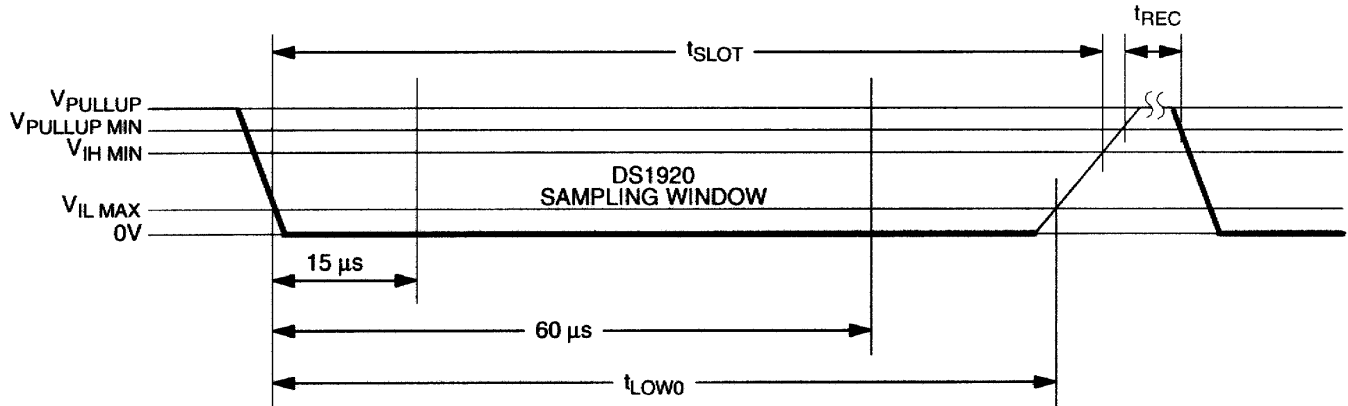
NOTES:

- Temperature conversion takes up to 0.75 seconds. After receiving the Convert Temperature command, the data line for the DS1920 must be held high for at least 0.75 seconds to provide power during the conversion process. As such, no other activity may take place on the 1-Wire bus for at least this period after a Convert Temperature command has been issued.
- After receiving the Copy Scratchpad command, the data line for the DS1920 must be held high for at least 10ms to provide power during the copy process. As such, no other activity may take place on the 1-Wire bus for at least this period after a Copy Scratchpad command has been issued.

READ/WRITE TIMING DIAGRAM Figure 11**Write-1 Time Slot**

READ/WRITE TIMING DIAGRAM (continued) Figure 11

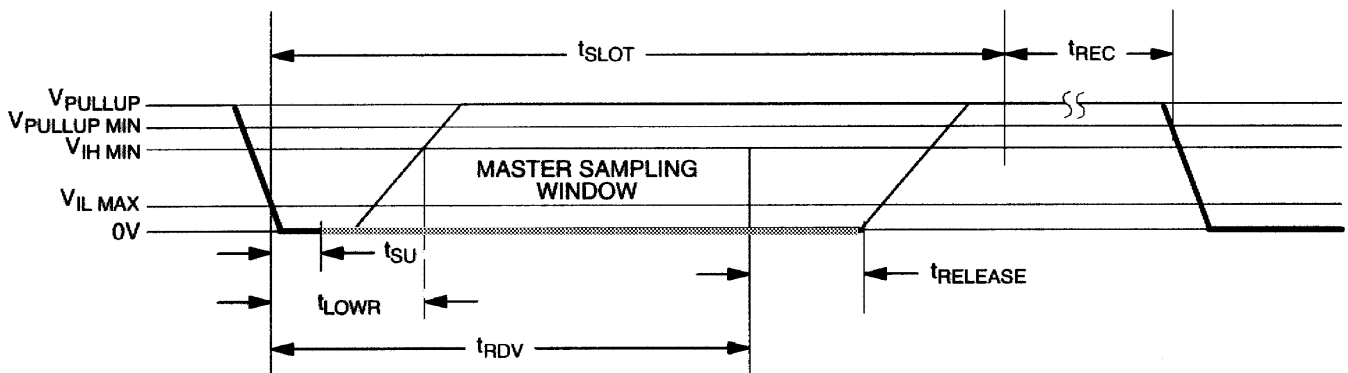
Write-0 Time Slot



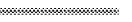


$$60\mu s \leq t_{LOW0} < t_{SLOT} < 120\mu s$$

$$1\mu s \leq t_{REC} < \infty$$

Read-Data Time Slot



	RESISTOR
	MASTER
	DS1920

$$60\mu s \leq t_{SLOT} < 120\mu s$$

$$1\mu s \leq t_{LOWR} < 15\mu s$$

$$0 \leq t_{RELEASE} < 45\mu s$$

$$1\mu s \leq t_{REC} < \infty$$

$$t_{RDV} = 15\mu s$$

$$t_{SU} < 1\mu s$$

MEMORY FUNCTION EXAMPLE Table 3

Example: Bus Master initiates temperature conversion, then reads temperature.

MASTER MODE	DATA (LSB FIRST)	COMMENTS
Tx	Reset	Reset pulse(480–960µs)
Rx	Presence	Presence pulse
Tx	55h	Issue “Match ROM” command
Tx	<64-bit ROM code>	Issue address for DS1920
Tx	44h	Issue “Convert Temperature” command
Tx	<DATA LINE HIGH>	Data line is held high for at least 0.75 seconds by bus master to allow conversion to complete.
Tx	Reset	Reset pulse
Rx	Presence	Presence pulse
Tx	55h	Issue “Match ROM” command
Tx	<64-bit ROM code>	Issue address for DS1920
Tx	BEh	Issue “Read Scratchpad” command.
Rx	<9 data bytes>	Read entire scratchpad plus CRC; the master now recalculates the CRC of the eight data bytes received from the scratchpad, compares the CRC calculated and the CRC read. If they match, the master continues; if not, this read operation is repeated.
Tx	Reset	Reset pulse
Rx	Presence	Presence pulse, done

ABSOLUTE MAXIMUM RATINGS

Voltage on Any Pin Relative to Ground
 Operating Temperature
 Storage Temperature

-0.5V to +7.0V
 -55°C to +100°C
 -55°C to +100°C

This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect device reliability.

DC ELECTRICAL CONDITIONS

($T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Pullup Voltage	V_{PUP}	I/O Functions	2.8	5.0	6.0	V	1, 2
		+1/2°C Accurate Temperature Conversions	4.3		6.0	V	
Logic 1	V_{IH}		2.2			V	2
Logic 0	V_{IL}		-0.3		0.8	V	2, 10

DC ELECTRICAL CHARACTERISTICS

($V_{PUP} = 4.3\text{V}$ to 6.0V , $T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Thermometer Error	t_{ERR}	0°C to +70 °C			1/2	°C	11
		-55°C to +0°C and +70 °C to +100 °C	SEE TYPICAL CURVE				
Active Current	I_{DD}			1000	1500	μA	3,4
Input Load Current	I_L			5		μA	
Output Logic Low at 4mA	V_{OL}				0.4	V	2

CAPACITANCE

($T_A = +25^\circ\text{C}$)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
I/O (1-Wire)	$C_{IN/OUT}$			800	pF	9

AC ELECTRICAL CHARACTERISTICS: TEMPERATURE CONVERSION AND COPY SCRATCHPAD

($V_{PUP} = 4.3\text{V}$ to 6.0V , $T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$.)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Temperature Conversion	t_{CONV}		0.2	0.75	seconds	
Copy Scratchpad	t_{COPY}			10	ms	5

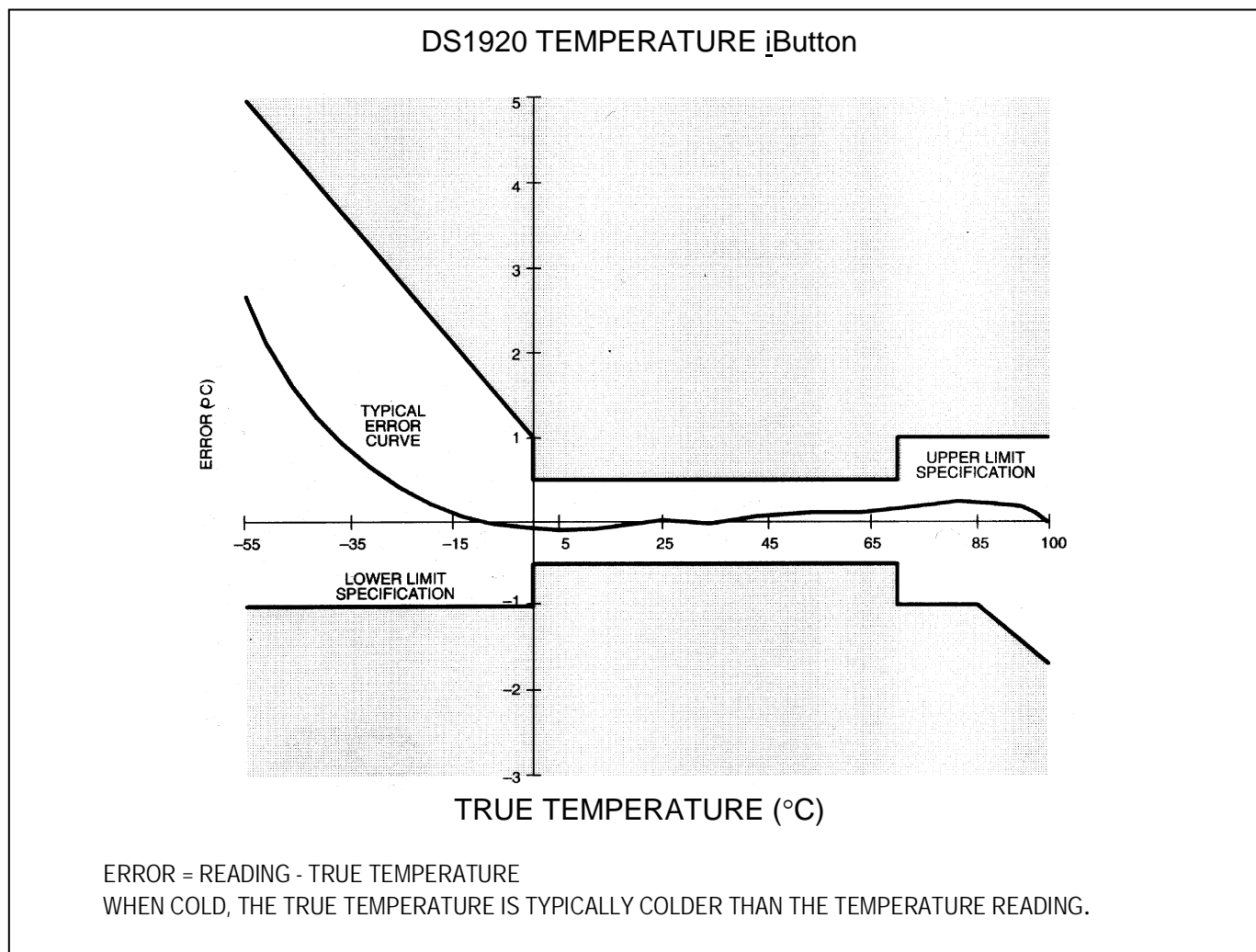
AC ELECTRICAL CHARACTERISTICS: 1-Wire INTERFACE(V_{PUP} = 2.8V to 6.0V, T_A = -55°C to +100°C.)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	NOTES
Time Slot	t _{SLOT}	60		120	μs	
Write 1 Low Time	t _{LOW1}	1		15	μs	
Write 0 Low Time	t _{LOW0}	60		120	μs	
Read Data Valid	t _{RDV}	exactly 15			μs	
Release Time	t _{RELEASE}	0	15	45	μs	
Read Data Setup	t _{SU}			1	μs	8
Recovery Time	t _{REC}	1			μs	
Reset Time High	t _{RSTH}	480			μs	
Reset Time Low	t _{RSTL}	480		4800	μs	6, 7
Presence Detect High	t _{PDHIGH}	15		60	μs	
Presence Detect Low	t _{PDLOW}	60		240	μs	

NOTES:

- Temperature conversion will work with $\pm 2^\circ\text{C}$ accuracy down to V_{PUP} = 3.4V.
- All voltages are referenced to ground.
- I_{DD} specified with low-impedance pullup to 5.0V.
- Active current refers to temperature conversion.
- Writing to EEPROM consumes approximately 200μA.
- t_{RSTL} may be up to 4800μs. With longer times, the result of temperature conversion may get lost.
- The reset low time should be restricted to a maximum of 960μs, to allow interrupt signaling, otherwise it could mask or conceal interrupt pulses.
- Read data setup time refers to the time the host must pull the 1-Wire bus low to read a bit. Data is guaranteed to be valid within 1μs of this falling edge and will remain valid for 14μs minimum (15μs total from falling edge on 1-Wire bus).
- Capacitance on the data contact could be 800pF when power is first applied. If a 5kΩ resistor is used to pull up the data line to V_{CC}, 5μs after power has been applied, the parasite capacitance will not affect normal communications.
- Under certain low-voltage conditions, V_{ILMAX} may have to be reduced to as much as 0.5V to always guarantee a presence pulse.
- See the *Typical Performance Curve* for specification limits outside the 0°C to +70°C range. Thermometer error reflects sensor accuracy as tested during calibration.

TYPICAL PERFORMANCE CURVE



PACKAGE INFORMATION

For the latest package outline information and land patterns, go to www.maxim-ic.com/packages.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
F5 MicroCAN	IB+5NS	21-0266

REVISION HISTORY

REVISION DATE	DESCRIPTION	PAGES CHANGED
082906	In the <i>Common iButton Features</i> , reworded the UL statement.	1
110806	Extended the temperature conversion time from 0.5s to 0.75s maximum.	11, 15, 16, 18, 19
040108	Removed F3 MicroCAN drawing and ordering information; added lead-free DS1920-F5+ and removed leaded package from the Ordering Information table.	1
8/09	Corrected the <i>Ordering Information</i> PART information (added hyphen to the part number).	1
	Removed the UL#913 bullet from the <i>Common iButton Features</i> section.	1



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

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- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
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- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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